NSN 5961-01-587-3514

Diode Semiconductor Device - Page 1 of 1



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Mounting Facility Quantity:
1
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
600.0 reverse voltage, peak and 600.0 working peak reverse voltage, peak total value
Current Rating Per Characteristic:
30.00 amperes forward current, dc and 70.00 amperes forward current, peak total value and 325.00 amperes peak forward surge curren
Power Rating Per Characteristic:
125.0 watts total device dissipation
Maximum Operating Tempurature Per Measurement Point:
175.0 degrees celsius ambient air
Terminal Type And Quantity:
2 pin
Shelf Life:
N/a
Unit Of Measure:

Demilitarization:
No
Fiig:
A110a0